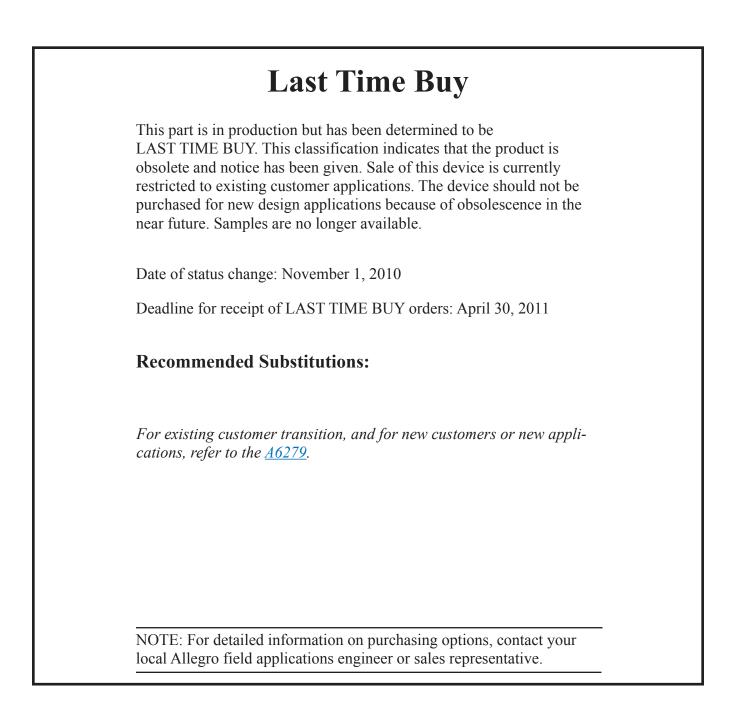


8-Bit Serial Input Constant-Current Latched LED Driver



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### 8-Bit Serial Input Constant-Current Latched LED Driver

#### **Features and Benefits**

- Up to 90 mA constant-current outputs
- Undervoltage lockout
- Low-power CMOS logic and latches
- High data-input rate
- Pin-compatible with TB62705CP

#### Packages



16-pin DIP (A package)



Not to scale

16-pin SOICW (LW package)

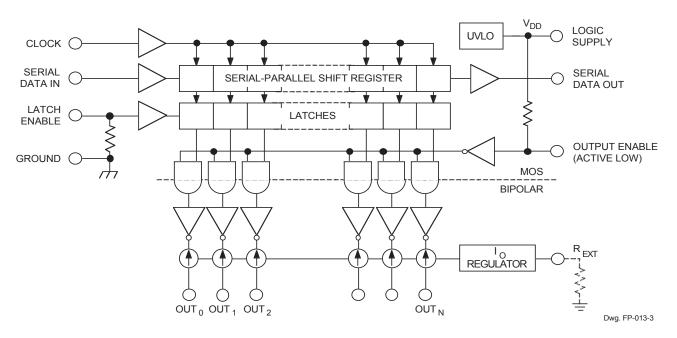


Description

The A6275 is specifically designed for LED display applications. Each BiCMOS device includes an 8-bit CMOS shift register, accompanying data latches, and eight NPN constant-current sink drivers.

The CMOS shift register and latches allow direct interfacing with microprocessor-based systems. With a 5 V logic supply, typical serial data-input rates are up to 20 MHz. The LED drive current is determined by the user selection of a single resistor. A CMOS serial data output permits cascade connections in applications requiring additional drive lines. For inter-digit blanking, all output drivers can be disabled with an ENABLE input high. A similar 150 mA output device is available as the A6277; a similar 16-bit device is available as the A6276.

Two package styles are provided: a through-hole DIP (suffix A) and a surface-mount SOICW (suffix LW). Under normal applications, copper leadframes and low logic-power dissipation allow these devices to sink maximum rated current through all outputs continuously over the operating temperature range (90 mA, 0.9 V drop, 85°C). Both packages are lead (Pb) free, with 100% matte tin leadframe plating.



#### **Functional Block Diagram**

#### Selection Guide

Part Number	Package	Packing	Ambient Temperature (°C)
A6275EA-T	16-pin DIP	25 per tube	-40 to 85
A6275ELWTR-T	16-pin SOICW	1000 per reel	-40 10 85
A6275SLWTR-T	16-pin SOICW	1000 per reel	–20 to 85

#### **Absolute Maximum Ratings\***

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V <sub>DD</sub>		7.0	V
Input Voltage Range	VI		-0.4 to V <sub>DD</sub> + 0.4	V
Output Voltage Range	Vo		–0.5 to V <sub>DD</sub> + 17	V
Output Current	Ι <sub>Ο</sub>		90	mA
Ground Current	I <sub>GND</sub>		750	mA
Operating Ambient Temperature	т	Range E	-40 to 85	°C
Operating Ambient Temperature	T <sub>A</sub>	Range S	-20 to 85	°C
Maximum Junction Temperature	T <sub>J</sub> (max)		150	°C
Storage Temperature	T <sub>stg</sub>		–55 to 150	°C

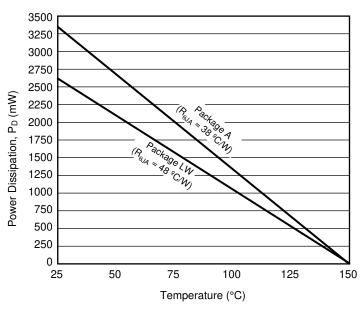
\*These CMOS devices have input static protection (Class 2) but are still susceptible to damage if exposed to extremely high static electrical charges.

#### Thermal Characteristics may require derating at maximum conditions, see application information

Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance		Package A, 4-layer PCB based on JEDEC standard		°C/W
Fackage memori Resistance	$R_{\theta JA}$	Package LW, 4-layer PCB based on JEDEC standard	48	°C/W

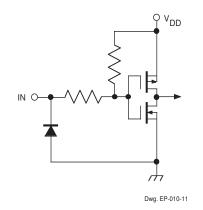
\*Additional thermal information available on the Allegro website.

#### Power Dissipation versus Ambient Temperature

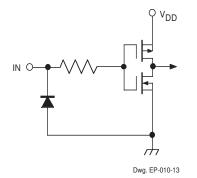




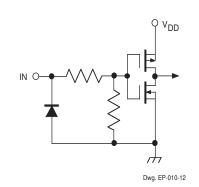
### Serial-Input Constant-Current Latched LED Driver with Open LED Detection and Dot Correction



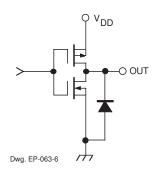
OUTPUT ENABLE (active low)







LATCH ENABLE



#### SERIAL DATA OUT

Serial		S	hift	Regi	ister	Cont	ents	Serial	Data Enable		Latch Contents			Output		Output Contents						
Data Input	Clock Input	I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>		I <sub>N-1</sub>	I <sub>N</sub>	Data Output			I <sub>2</sub>	I <sub>3</sub>		I <sub>N-1</sub>	I <sub>N</sub>	Enable Input	I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>		I <sub>N-1</sub>	I <sub>N</sub>
Н	Г	н	R <sub>1</sub>	R <sub>2</sub>		R <sub>N-2</sub>	R <sub>N-1</sub>	R <sub>N-1</sub>														
L	Г	L	R <sub>1</sub>	$R_2$		R <sub>N-2</sub>	R <sub>N-1</sub>	R <sub>N-1</sub>														
Х	l	R <sub>1</sub>	$R_2$	R <sub>3</sub>		R <sub>N-1</sub>	R <sub>N</sub>	R <sub>N</sub>														
		х	Х	Х		Х	Х	х	L	R <sub>1</sub>	$R_2$	R <sub>3</sub>		R <sub>N-1</sub>	$R_N$							
		Р <sub>1</sub>	P <sub>2</sub>	P <sub>3</sub>		P <sub>N-1</sub>	P <sub>N</sub>	P <sub>N</sub>	Н	Р <sub>1</sub>	P <sub>2</sub>	P <sub>3</sub>		P <sub>N-1</sub>	$P_N$	L	P <sub>1</sub>	P <sub>2</sub>	$P_3$		P <sub>N-1</sub>	P <sub>N</sub>
										Х	Х	Х		Х	Х	н	Н	Н	Н		Н	Н

**TRUTH TABLE** 

L = Low Logic (Voltage) Level H = High Logic (Voltage) Level X = Irrelevant P = Present State R = Previous State



### ELECTRICAL CHARACTERISTICS at $T_A = +25^{\circ}C$ , $V_{DD} = 5 V$ (unless otherwise noted).

				Lim	its	
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Supply Voltage Range	V <sub>DD</sub>	Operating	4.5	5.0	5.5	V
Undervoltage Lockout	V <sub>DD(UV)</sub>	$V_{DD}$ = 0 $\rightarrow$ 5 V	3.4	_	4.0	V
Output Current	Ι <sub>ο</sub>	$V_{CE}$ = 0.7 V, $R_{EXT}$ = 250 $\Omega$	64.2	75.5	86.8	mA
(any single output)		$V_{CE}$ = 0.7 V, $R_{EXT}$ = 470 $\Omega$	34.1	40.0	45.9	mA
Output Current Matching	Δl <sub>O</sub>	$0.4 \text{ V} \le \text{V}_{\text{CE}(A)} = \text{V}_{\text{CE}(B)} \le 0.7 \text{ V}$ :				
(difference between any		R <sub>EXT</sub> = 250 Ω	_	±1.5	±6.0	%
two outputs at same $V_{CE}$ )		R <sub>EXT</sub> = 470 Ω	_	±1.5	±6.0	%
Output Leakage Current	I <sub>CEX</sub>	V <sub>OH</sub> = 15 V	_	1.0	5.0	μA
Logic Input Voltage	V <sub>IH</sub>		0.7V <sub>DD</sub>	_	$V_{DD}$	V
	VIL		GND	_	$0.3V_{DD}$	V
SERIAL DATA OUT	V <sub>OL</sub>	I <sub>OL</sub> = 500 μA	-	_	0.4	V
Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -500 μA	4.6	_	_	V
Input Resistance	RI	ENABLE Input, Pull Up	150	300	600	kΩ
		LATCH Input, Pull Down	100	200	400	kΩ
Supply Current	I <sub>DD(OFF)</sub>	$R_{EXT}$ = open, $V_{OE}$ = 5 V	_	0.8	1.4	mA
		$R_{EXT}$ = 470 $\Omega$ , $V_{OE}$ = 5 V	3.5	6.0	8.0	mA
		$R_{EXT}$ = 250 $\Omega$ , $V_{OE}$ = 5 V	6.5	11	15	mA
	I <sub>DD(ON)</sub>	$R_{EXT}$ = 470 $\Omega$ , $V_{OE}$ = 0 V	5.0	10	14	mA
		R <sub>EXT</sub> = 250 Ω, V <sub>OE</sub> = 0 V	8.0	16	24	mA

Typical Data is at  $V_{DD}$  = 5 V and is for design information only.



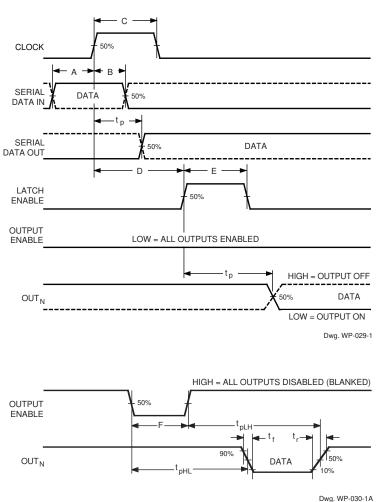
## SWITCHING CHARACTERISTICS at $T_A = 25^{\circ}C$ , $V_{DD} = V_{IH} = 5 V$ , $V_{CE} = 0.4 V$ , $V_{IL} = 0 V$ , $R_{EXT} = 470 \Omega$ , $I_O = 40 \text{ mA}$ , $V_L = 3 V$ , $R_L = 65 \Omega$ , $C_L = 10.5 \text{ pF}$ .

				Li	imits	
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Propagation Delay Time	t <sub>pHL</sub>	CLOCK-OUT <sub>n</sub>	_	350	1000	ns
		LATCH-OUT <sub>n</sub>	_	350	1000	ns
		ENABLE-OUT <sub>n</sub>	_	350	1000	ns
		CLOCK-SERIAL DATA OUT	_	40	_	ns
Propagation Delay Time	t <sub>pLH</sub>	CLOCK-OUT <sub>n</sub>	_	300	1000	ns
		LATCH-OUT <sub>n</sub>	-	300	1000	ns
		ENABLE-OUT <sub>n</sub>	_	300	1000	ns
		CLOCK-SERIAL DATA OUT	_	40	_	ns
Output Fall Time	t <sub>f</sub>	90% to 10% voltage	150	350	1000	ns
Output Rise Time	tr	10% to 90% voltage	150	300	600	ns

#### **RECOMMENDED OPERATING CONDITIONS**

Characteristic	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	V <sub>DD</sub>		4.5	5.0	5.5	V
Output Voltage	Vo		-	1.0	4.0	V
Output Current	Ι <sub>ο</sub>	Continuous, any one output	_	_	90	mA
	I <sub>он</sub>	SERIAL DATA OUT	-	_	-1.0	mA
	I <sub>OL</sub>	SERIAL DATA OUT	_	_	1.0	mA
Logic Input Voltage	V <sub>IH</sub>		0.7V <sub>DD</sub>	_	V <sub>DD</sub> + 0.3	V
	V <sub>IL</sub>		-0.3	_	0.3V <sub>DD</sub>	V
Clock Frequency	f <sub>CK</sub>	Cascade operation	_	_	10	MHz





TIMING REQUIREMENTS and SPECIFICATIONS

(Logic Levels are  $V_{DD}$  and Ground)

<ul> <li>A. Data Active Time Before Clock Pulse (Data Set-Up Time), t<sub>su(D)</sub></li></ul>
(Data Hold Time), $t_{h(D)}$
<b>D.</b> Time Between Clock Activation
and Latch Enable, t <sub>su(L)</sub> 100 ns
<b>E.</b> Latch Enable Pulse Width, $t_{w(L)}$ 100 ns
<b>F.</b> Output Enable Pulse Width, $t_{w(OE)}$ <b>4.5</b> µs
NOTE: Timing is representative of a 10 MHz clock. Sig- nificantly higher speeds are attainable. Max. Clock Transition Time, $t_r$ or $t_f$ 10 µs

Serial data present at the input is transferred to the shift register on the logic 0-to-logic 1 transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUTPUT. The serial data must appear at the input prior to the rising edge of the CLOCK input waveform.

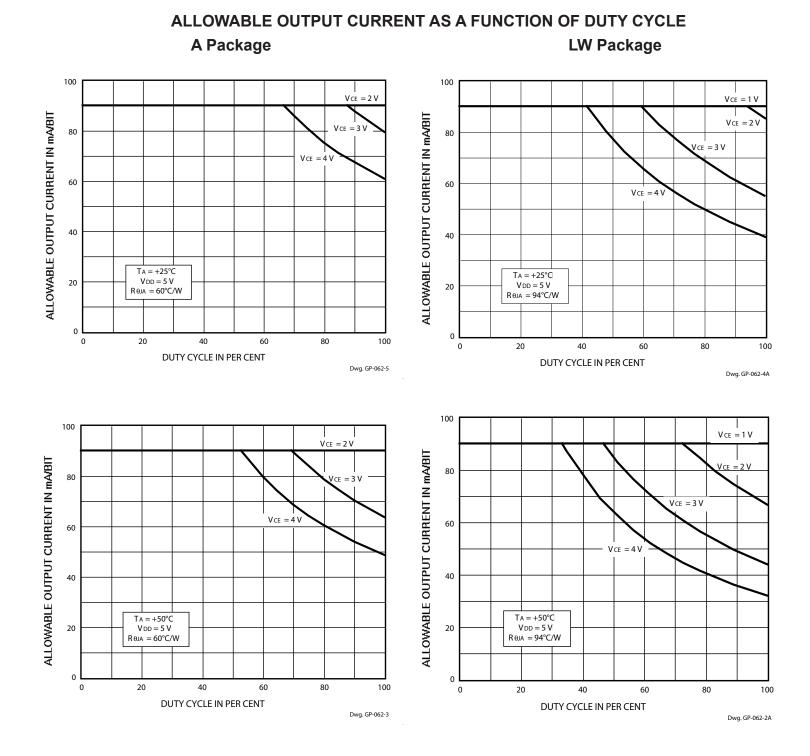
Information present at any register is transferred to the respective latch when the LATCH ENABLE is high (serial-to-parallel conversion). The latches continue to accept new data as

long as the LATCH ENABLE is held high. Applications where the latches are bypassed (LATCH ENABLE tied high) will require that the OUTPUT ENABLE input be high during serial data entry.

When the OUTPUT ENABLE input is high, the output sink drivers are disabled (OFF). The information stored in the latches is not affected by the OUTPUT ENABLE input. With the OUT-PUT ENABLE input low, the outputs are controlled by the state of their respective latches.



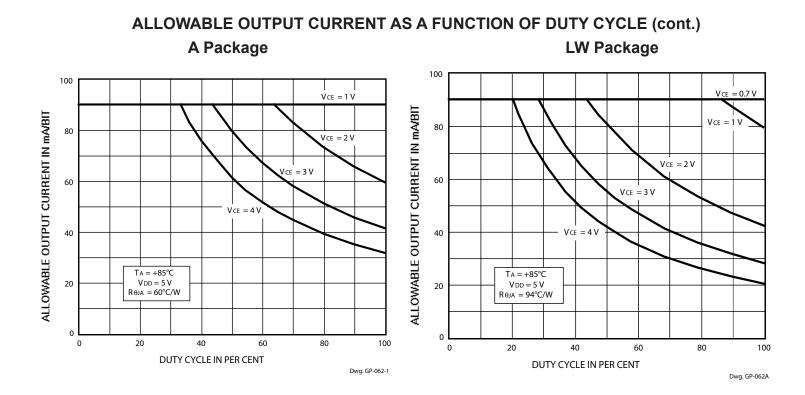
### Serial-Input Constant-Current Latched LED Driver with Open LED Detection and Dot Correction



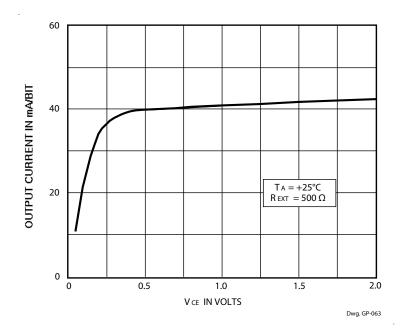


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### Serial-Input Constant-Current Latched LED Driver with Open LED Detection and Dot Correction

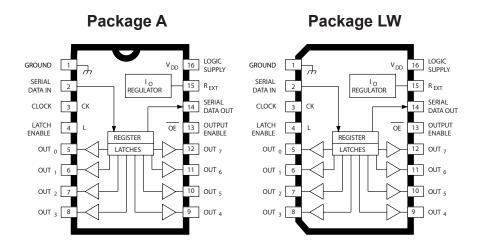


**TYPICAL CHARACTERISTICS** 





#### **Pin-out Diagrams**



#### **TERMINAL DESCRIPTION**

Terminal No.	Terminal Name	Function
1	GND	Reference terminal for control logic.
2	SERIAL DATA IN	Serial-data input to the shift-register.
3	CLOCK	Clock input terminal for data shift on rising edge.
4	LATCH ENABLE	Data strobe input terminal; serial data is latched with high-level input.
5-12	OUT <sub>0-7</sub>	The eight current-sinking output terminals.
13	OUTPUT ENABLE	When (active) low, the output drivers are enabled; when high, all output drivers are turned OFF (blanked).
14	SERIAL DATA OUT	CMOS serial-data output to the following shift-register.
15	R <sub>EXT</sub>	An external resistor at this terminal establishes the output current for all sink drivers.
16	SUPPLY	(V <sub>DD</sub> ) The logic supply voltage (typically 5 V).



### Serial-Input Constant-Current Latched LED Driver with Open LED Detection and Dot Correction

**Applications Information** 

#### 100 Vce = 0.7 V 80 OUTPUT CURRENT IN mA/BIT 60 40 20 0 100 2 k 3 k 200 300 500 700 1 k CURRENT-CONTROL RESISTANCE, R EXT IN OHMS Dwg. GP-061

The load current per bit  $(I_0)$  is set by the external resistor

 $(R_{EXT})$  as shown in the figure below.

Package Power Dissipation (P<sub>D</sub>). The maximum allowable package power dissipation is determined as  $P_D(max) = (150 - T_A)/R_{\theta JA}$ . The actual package power dissipation is  $P_D(act) = dc(V_{CE} \times I_O \times 8) + (V_{DD} \times I_{DD})$ .

When the load supply voltage is greater than 3 V to 5 V, considering the package power dissipating limits of these devices, or if  $P_D(act) > P_D(max)$ , an external voltage reducer (V<sub>DROP</sub>) should be used.

**Load Supply Voltage (V**<sub>LED</sub>). These devices are designed to operate with driver voltage drops ( $V_{CE}$ ) of 0.4 V to 0.7 V with LED forward voltages ( $V_F$ ) of 1.2 V to 4.0 V. If higher voltages are dropped across the driver, package power dissipation will be increased significantly. To minimize package power dissipation, it is recommended to use the lowest possible load supply voltage or to set any series dropping voltage ( $V_{DROP}$ ) as

 $V_{DROP} = V_{LED} - V_F - V_{CE}$ with  $V_{DROP} = I_o \times R_{DROP}$  for a single driver, or a Zener diode (V<sub>Z</sub>), or a series string of diodes (approximately

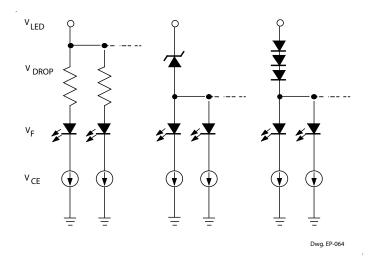
# 0.7 V per diode) for a group of drivers. If the available voltage source will cause unacceptable dissipation and series resistors or diode(s) are undesirable, a regulator such as the Sanken Series SAI or Series SI can be used to

For reference, typical LED forward voltages are:

provide supply voltages as low as 3.3 V.

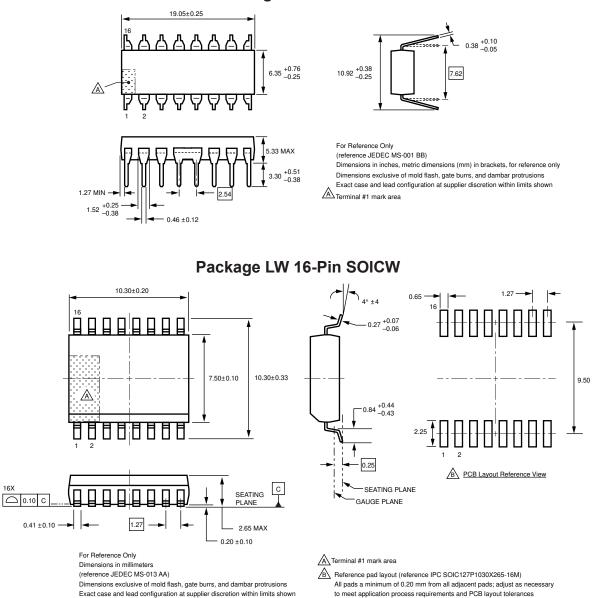
renered, cyprear EEE	101110110100800
White	3.5 - 4.0 V
Blue	3.0 - 4.0 V
Green	1.8 - 2.2 V
Yellow	2.0 - 2.1 V
Amber	1.9 – 2.65 V
Red	1.6 – 2.25 V
Infrared	1.2 – 1.5 V

**Pattern Layout.** This device has a common logic-ground and power-ground terminal. If ground pattern layout contains large common-mode resistance, and the voltage between the system ground and the LATCH ENABLE or CLOCK terminals exceeds 2.5 V (because of switching noise), these devices may not operate correctly.





Package A 16-Pin DIP



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